NSN 5961-00-315-9567

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View Online at https://aerobasegroup.com/nsn/5961-00-315-9567 **Inclosure Material:** Ceramic **Overall Length:** 0.635 inches **Overall Height:** 0.635 inches **Overall Width:** 0.380 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 17.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ferrule Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

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